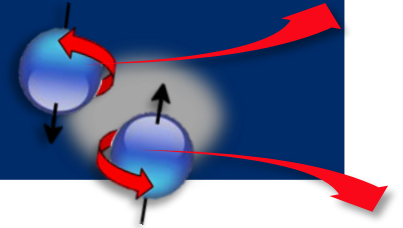


# THEORY OF SPIN HALL EFFECT AND INTERFACE SPIN-ORBIT COUPLING



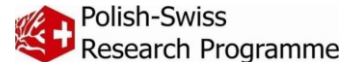
Anna Dyrdał, Łukasz Karwacki,

Józef Barnaś

*Mesoscopic Physics Division, Faculty of Physics  
Adam Mickiewicz University in Poznań, Poland*

**NANOSPIN: Nanoscale spin torque devices for spin electronics**

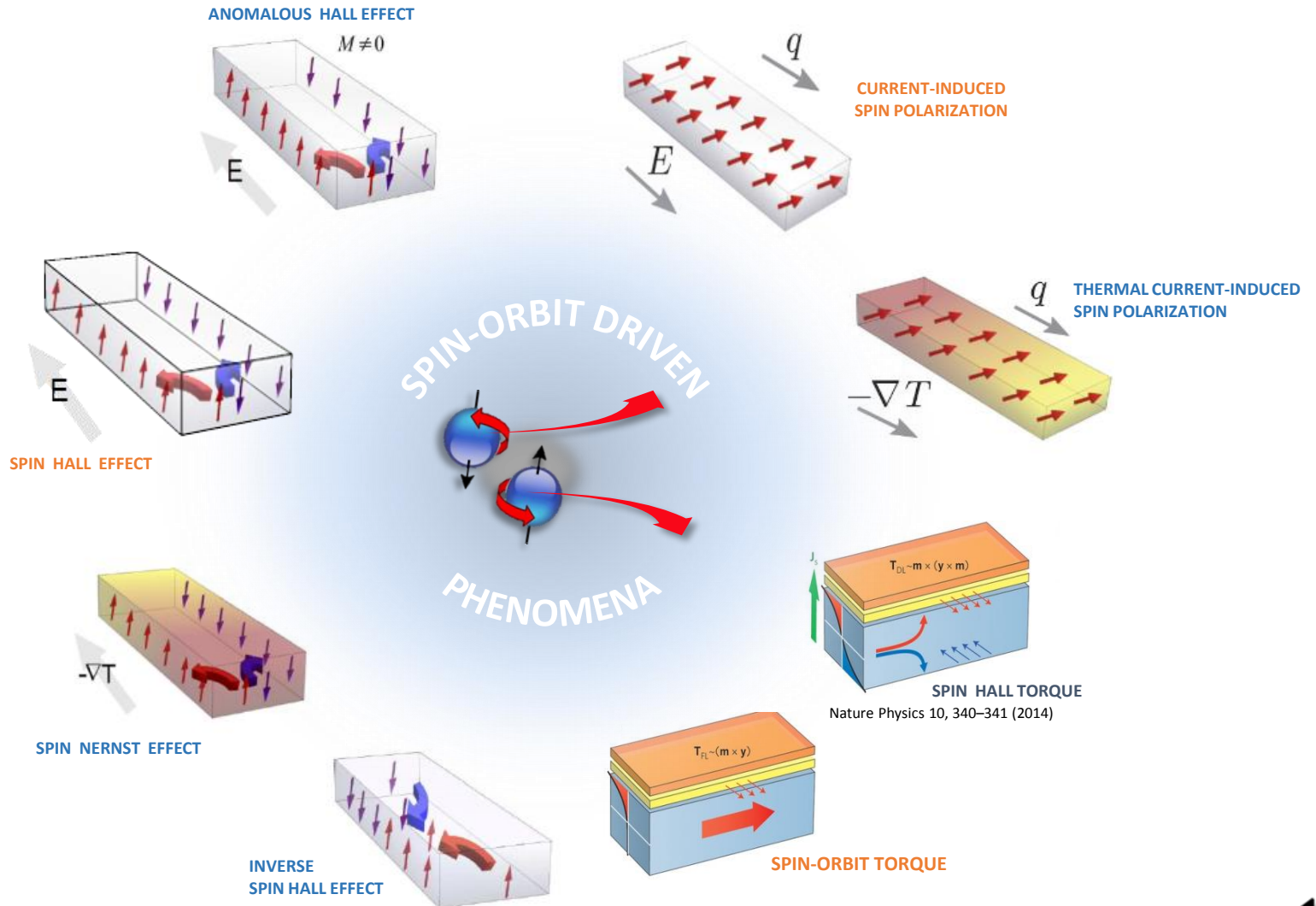
Summarizing MEETING, 11th-12th of July 2016



# OUTLINE

- INTRODUCTION: SPIN ORBIT DRIVEN PHENOMENA
  - MICROSCOPIC MECHANISMS LEADING TO AHE/SHE
  - SPIN TORQUES DUE TO SPIN-ORBIT COUPLING
  - SHE AND CISP IN SEMICONDUCTOR HETEROSTRUCTURES WITH RASHBA SOI
- DETERMINATION OF SPIN-ORBIT TORQUES:  
THEORETICAL DESCRIPTION OF HARMONIC HALL VOLTAGE MEASUREMENTS
- PHENOMENOLOGICAL DESCRIPTION OF SOTs
  - DRIFT-DIFFUSION MODEL FOR Ta|CoFeB
    - literature – model for Ta|CoFeB by Kim et.al.
    - results for trilayer spin-diffusion model of Ta|interface|CoFeB
  - TRILAYER SPIN-DIFFUSION MODEL: SUMMARY
  - AHE IN Ta|CoFeB
  - ANOTHER APPROACHES

# SPIN-ORBIT DRIVEN PHENOMENA



# MICROSCOPIC MECHANISMS

## INTRINSIC CONTRIBUTION

### BAND STRUCTURE TOPOLOGY

An external electric field leads to an interband coherence that gives rise to contribution to the transverse velocity – an anomalous velocity related to Berry phase curvature

$$v_y = \frac{\partial \epsilon_{n\mathbf{k}}}{\partial k_y} - \underbrace{eE_x \mathcal{F}_z^n}_{\text{anomalous velocity}}$$

$$\hat{H}_{SO} = -\frac{1}{4m^2c^2} \hat{\sigma} \cdot (\mathbf{p} \times \nabla V)$$

$$\hat{H}_E = e\mathbf{E} \cdot \hat{\mathbf{r}} \quad \langle u_{n\mathbf{k}} | \hat{H}_E | u_{\bar{n}\mathbf{k}} \rangle = ie\mathbf{E} \cdot \langle u_{n\mathbf{k}} | \frac{\partial u_{\bar{n}\mathbf{k}}}{\partial \mathbf{k}} \rangle \neq 0 \quad \bar{n} \neq n$$

$$\hat{H}_0 \rightarrow |u_{n\mathbf{k}}\rangle$$

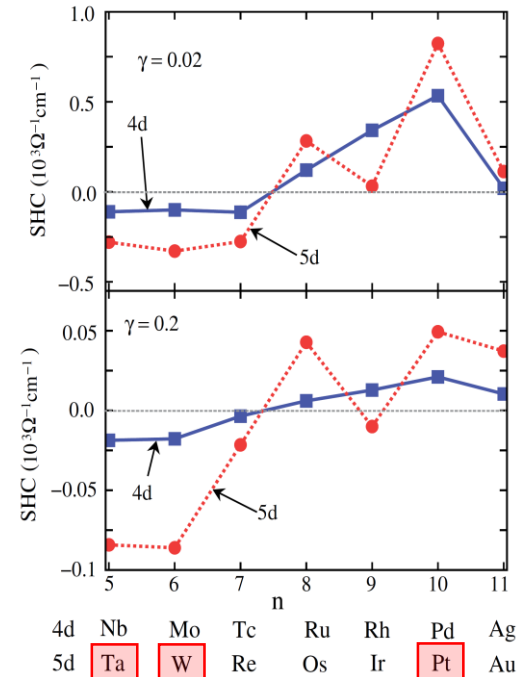
$$\hat{H} = \hat{H}_0 + eE_x \hat{x} \rightarrow |u'_{n\mathbf{k}}\rangle = |u_{n\mathbf{k}}\rangle + ieE_x \sum_{\bar{n} \neq n} \frac{\langle u_{\bar{n}\mathbf{k}} | \frac{\partial u_{n\mathbf{k}}}{\partial k_x} \rangle}{\epsilon_{n\mathbf{k}} - \epsilon_{\bar{n}\mathbf{k}}} |u_{\bar{n}\mathbf{k}}\rangle$$

$$\Psi'_{n\mathbf{k}\mathbf{c}}(\mathbf{r}, t) = e^{-i\hat{H}t} \Psi'_{n\mathbf{k}\mathbf{c}}(\mathbf{r})$$

$$\Psi'_{n\mathbf{k}\mathbf{c}}(\mathbf{r}) = \int \frac{d^D \mathbf{k}}{L^{D/2}} a(\mathbf{k}) \exp\{i(\mathbf{k} \cdot \mathbf{r})\} |u'_{n\mathbf{k}}\rangle$$

$$v_y = \frac{d}{dt} \langle \Psi'_{n\mathbf{k}\mathbf{c}}(\mathbf{r}, t) | \hat{y} | \Psi'_{n\mathbf{k}\mathbf{c}}(\mathbf{r}, t) \rangle = \langle u'_{n\mathbf{k}} | -i \left[ i \frac{\partial}{\partial k_y}, H_0 \right] | u'_{n\mathbf{k}} \rangle$$

$$= \frac{\partial \epsilon_{n\mathbf{k}}}{\partial k_y} + ieE_x \left( \langle \frac{\partial u_{n\mathbf{k}}}{\partial k_y} | \frac{\partial u_{n\mathbf{k}}}{\partial k_x} \rangle - \langle \frac{\partial u_{n\mathbf{k}}}{\partial k_x} | \frac{\partial u_{n\mathbf{k}}}{\partial k_y} \rangle \right)$$



Intrinsic spin Hall conductivity for 4d and 5d transition metals (microscopic tight-binding calculations);

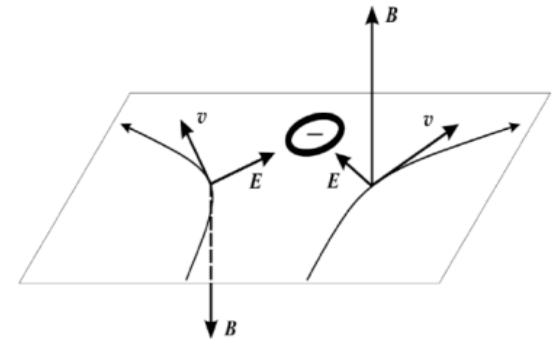
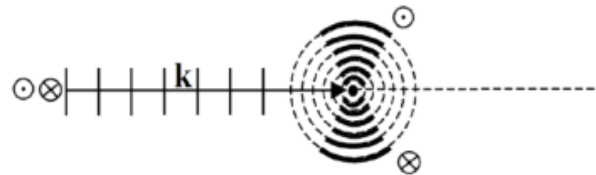
$\gamma$  – a quasiparticle damping rate

Tanaka, T., H. Kontani, M. Naito, T. Naito, D. Hirashima, K. Yamada, and J. Inoue, 2008, Phys. Rev. B 77, 165117.

# MICROSCOPIC MECHANISMS

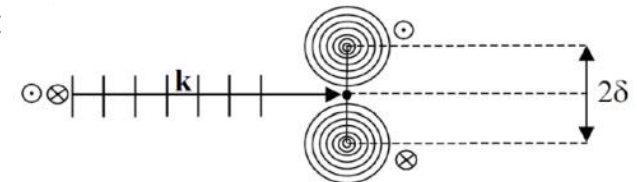
## EXTRINSIC CONTRIBUTION

### ✓ SKEW SCATTERING



### ✓ SIDE JUMP

- **EXTRINSIC SIDE-JUMP:** The contribution arising from the non-spin-orbit coupled part of the wave-packet scattering off the spin-orbit coupled disordered.
- **INTRINSIC SIDE-JUMP:** The contribution arising from the spin-orbit coupled part of the wave-packet formed by the Bloch electrons scattering off the scalar potential alone without spin-orbit coupling.

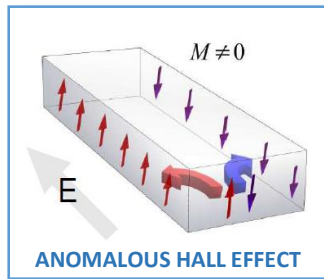


J. Sinova et al., Rev. Mod Phys. 87, 1213 (2015); G. Vignale, J. Supercond. Novel Magn. 23, 3 (2010);  
J. Schliemann, Int. J. Mod. Phys. B 20, 1015 (2006); A. Crépieux, P. Bruno, Phys. Rev. B 64, 014416 (2001);  
M. I. Dyakonov and A. V. Khaetskii, in *Spin Physics in Semiconductors*  
edited by M. I. Dyakonov, Springer-Verlag, Berlin, Heidelberg, 2008, Chap. 8;

# MICROSCOPIC MECHANISMS: EXPERIMENTAL DATA vs THEORY

$$\sigma_{xy} = \sigma_{xy}^{\text{int}} + \sigma_{xy}^{\text{sj}} + \sigma_{xy}^{\text{ss}}$$

$\sim \tau^0$                        $\sim \tau^1$   
 $(\sim \sigma_{xx}^0)$                        $(\sim \sigma_{xx}^1)$



## HIGH CONDUCTIVITY REGIME

$$\sigma_{xx} > 0.5 \times 10^6 (\Omega \text{ cm})^{-1}$$

$$\sigma_{xy}^{\text{AH}} \sim \sigma_{xx}$$

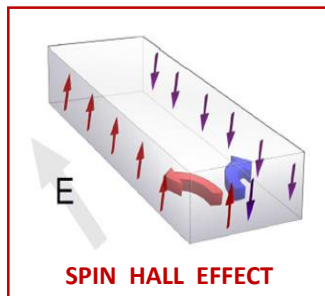
*skew-scattering  
mechanism dominate*

## GOOD METAL REGIME

$$\sigma_{xx} \sim 10^4 - 10^6 (\Omega \text{ cm})^{-1}$$

$$\sigma_{xy}^{\text{AH}} \sim \sigma_{xx}^0$$

*scattering-independent  
mechanisms or side jump  
dominate*



## BAD-METAL-HOPPING REGIME

$$\sigma_{xx} < 10^4 (\Omega \text{ cm})^{-1}$$

$$\sigma_{xy}^{\text{AH}} \sim \sigma_{xx}^{1.6-1.8}$$

*there is currently no theory  
which predicts the observed  
scaling*

# CISP IN 2D ELECTRON GAS WITH RASHBA SOI

$$H = \sum_{\mathbf{k}} \psi_{\mathbf{k}}^\dagger H_{\mathbf{k}} \psi_{\mathbf{k}}$$

$$H_{\mathbf{k}} = \frac{\hbar^2 k^2}{2m} + H_{RSO}$$

$$H_{RSO} = \alpha(k_y \sigma_x - k_x \sigma_y)$$

$$H_{SO} = \frac{\hbar}{2} \vec{B}_{eff}(\vec{k}) \cdot \vec{\sigma}$$

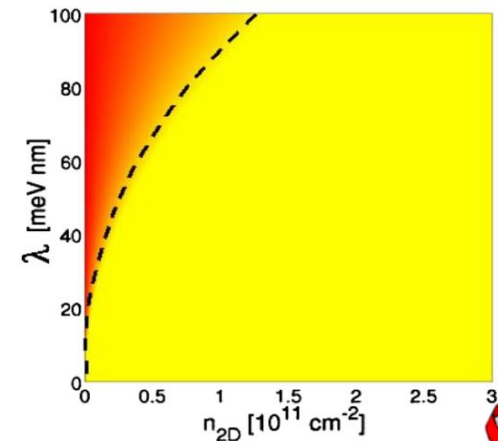
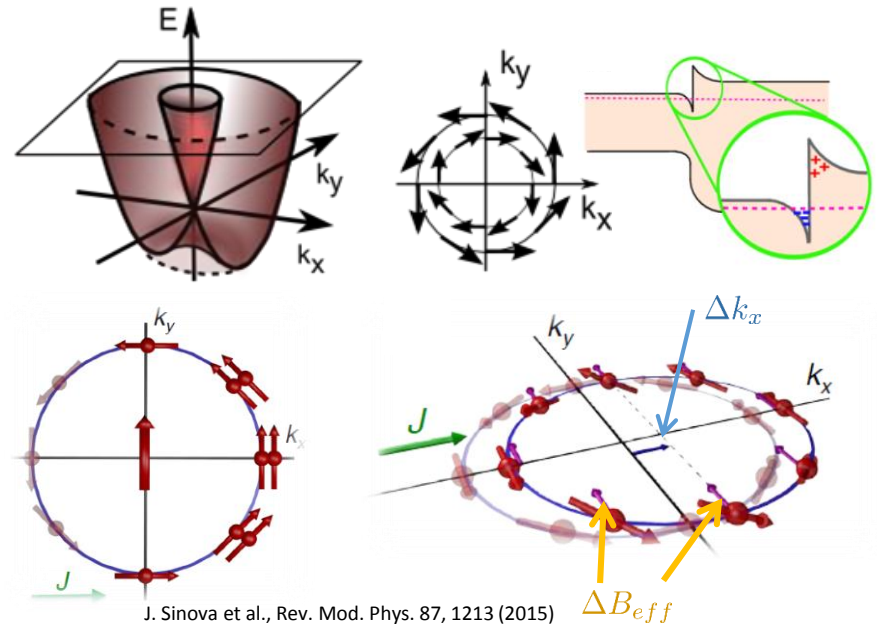
$$\vec{B}_{eff}(\vec{k}) = \frac{2\alpha}{\hbar} (k_y, -k_x, 0)$$

$$\vec{B}_{eff}(\vec{k}) \sim -\vec{k} \times \vec{E} \quad \vec{E} = -\frac{1}{e} \nabla V(\vec{r})$$

$\mu > 0$ :

$$\sigma_{xy}^{sz} = \frac{e}{8\pi}$$

$$S_x = \kappa \frac{1}{2} \alpha e E_y \frac{m}{2\pi \hbar^2} \tau$$



J. Sinova et al., Phys. Rev. Lett. 92, 126603 (2004)

N. A. Sinitsyn et al., Phys. Rev. B 70, 081312(R) (2004)

V.M. Edelstein, Sol. State Communs. 73, 233 (1990)

C. Gorini et al., Phys. Rev. B 78, 125327 (2008)

P. Schwab et al., Phys. Rev. B, Europhysics Lett. 90, 67004 (2010)

L. Golub et al., Phys. Rev. B 84, 115303 (2011)

A. Dyrda et al., Phys. Rev. B 87, 245309 (2013)

# SPIN-ORBIT TORQUES

## LLG EQUATION:

$$\frac{\partial \mathbf{M}}{\partial t} = \gamma_e \mathbf{M} \times (\mathbf{B}_{\text{ext}} + \mathbf{B}_{\text{exc}} + \mathbf{B}_{\text{an}} + \mathbf{B}_{\text{SO}}) + \frac{\lambda_{\text{eff}}}{M_s} \mathbf{M} \times \frac{\partial \mathbf{M}}{\partial t} - \frac{1}{(1 + \beta^2) M_s^2} \mathbf{M} \times [\mathbf{M} \times (\mathbf{u} \cdot \nabla) \mathbf{M}] - \frac{\beta}{(1 + \beta^2) M_s} \mathbf{M} \times (\mathbf{u} \cdot \nabla) \mathbf{M}.$$

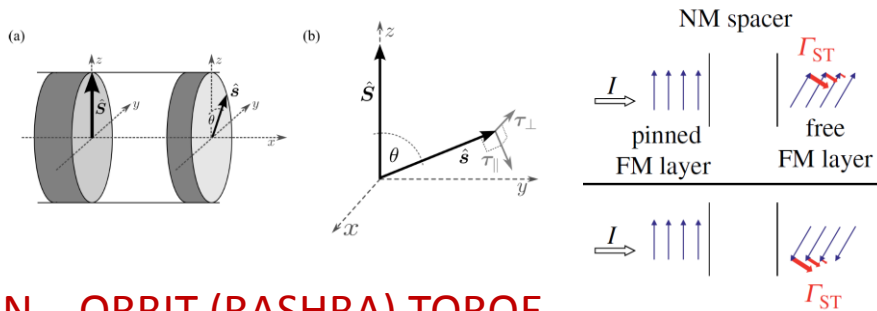
$$\mathbf{u} = (\mu_B P / e M_s) \mathbf{j}$$

$$\gamma_e = -e / m_e$$

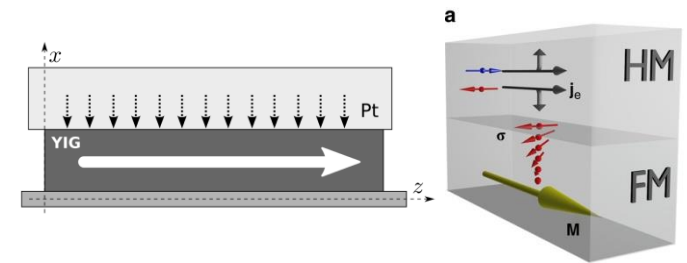
$$\beta = \hbar / (J \tau_{\text{sf}})$$

$$\lambda_{\text{eff}} = \lambda_G + \lambda_{\text{SP}}$$

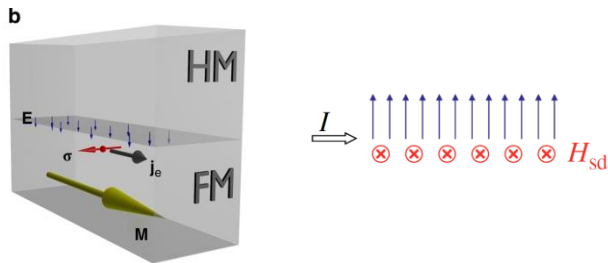
## SPIN TRANSFER TORQUE IN SPIN VALVES



## SPIN – HALL TORQUE



## SPIN – ORBIT (RASHBA) TORQUE



- . Sinova et al., Rev. Mod Phys. 87, 1213 (2015);
- X. Fan et al., Nature Communications 4, 1799 (2013);
- P. Gambardella, I. M. Miron, Phil. Trans. R. Soc. A, 369, 3175 (2011);



# DETERMINATION OF THE SOTs

## □ HARMONIC HALL VOLTAGE MEASUREMENTS

- M. Hayashi, J. Kim, M. Yamanouchi, and H. Ohno,  
"Quantitative characterization of the spin-orbit torque using harmonic Hall voltage measurements",  
PHYSICAL REVIEW B **89**, 144425 (2014)
- J. Kim, J. Sinha, M. Hayashi, M. Yamanouchi, S. Fukami, T. Suzuki, S. Mitani and H. Ohno,  
"Layer thickness dependence of the current-induced effective field vector in Ta | CoFeB | MgO",  
NATURE MATERIALS **12**, 240 (2013)

$$E = -K_{EFF} \cos^2 \theta - K_I \sin^2 \varphi \sin^2 \theta - \vec{M} \cdot \vec{H}$$

$$\vec{M} = M_S \hat{m}, \quad \hat{m} = (\sin \theta \cos \varphi, \sin \theta \sin \varphi, \cos \theta),$$

$$\vec{H} = H (\sin \theta_H \cos \varphi_H, \sin \theta_H \sin \varphi_H, \cos \theta_H)$$

$$\begin{aligned} \frac{\partial E}{\partial \theta} &= 0 \\ \frac{\partial E}{\partial \varphi} &= 0 \end{aligned} \Rightarrow (\theta_0, \varphi_0)$$

$$\Delta \theta = \frac{\partial \theta}{\partial H_X} \Delta H_X + \frac{\partial \theta}{\partial H_Y} \Delta H_Y + \frac{\partial \theta}{\partial H_Z} \Delta H_Z$$

$$\Delta \varphi = \frac{\partial \varphi}{\partial H_X} \Delta H_X + \frac{\partial \varphi}{\partial H_Y} \Delta H_Y + \frac{\partial \varphi}{\partial H_Z} \Delta H_Z$$

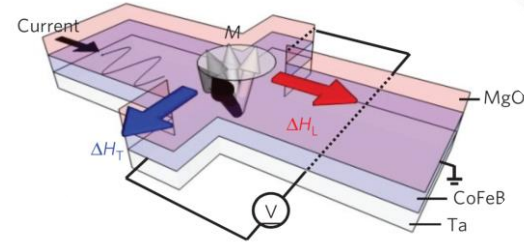
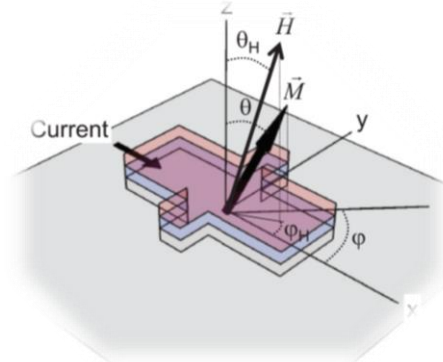
$$\begin{aligned} \frac{\partial}{\partial H_i} \left( \frac{\partial E}{\partial \theta} \right) &= 0 \\ \frac{\partial}{\partial H_i} \left( \frac{\partial E}{\partial \varphi} \right) &= 0 \end{aligned} \Rightarrow \frac{\partial \theta}{\partial H_i}, \frac{\partial \varphi}{\partial H_i}$$

$$\Delta \theta = \frac{\cos \theta_0 (\Delta H_X \cos \varphi_H + \Delta H_Y \sin \varphi_H) - \sin \theta_0 \Delta H_Z}{(H_K - H_A \sin^2 \varphi_H) \cos 2\theta_0 + H \cos (\theta_H - \theta_0)}$$

$$\Delta \varphi = \frac{-\Delta H_X \sin \varphi_H + \Delta H_Y \cos \varphi_H}{-H_A \sin \theta_0 \cos 2\varphi_H + H \sin \theta_H}$$

$$H_K \equiv \frac{2K_{EFF}}{M_S}, \quad H_A \equiv \frac{2K_I}{M_S}$$

$$|H_A| \ll |H \sin \theta_H|, \quad \varphi_0 = \varphi_H$$



$$R_{XY} = \frac{1}{2} \Delta R_A \cos \theta + \frac{1}{2} \Delta R_P \sin^2 \theta \sin 2\varphi$$

$$\theta = \theta_0 + \Delta \theta, \varphi = \varphi_0 + \Delta \varphi$$

$$R_{XY} \approx \frac{1}{2} \Delta R_A (\cos \theta_0 - \Delta \theta \sin \theta_0)$$

$$+ \frac{1}{2} \Delta R_P (\sin^2 \theta_0 + \Delta \theta \sin 2\theta_0) (\sin 2\varphi_0 + 2\Delta \varphi \cos 2\varphi_0) \Delta \varphi, \Delta \theta \ll 1$$

$$V_{XY} = R_{XY} I$$

$$I = \Delta I \sin \omega t$$

$$V_{XY} = V_0 + V_\omega \sin \omega t + V_{2\omega} \cos 2\omega t,$$

$$V_0 = \frac{1}{2} (B_\theta + B_\varphi) \Delta I,$$

$$V_\omega = A \Delta I,$$

$$V_{2\omega} = -\frac{1}{2} (B_\theta + B_\varphi) \Delta I,$$

$$A = \frac{1}{2} \Delta R_A \cos \theta_0 + \frac{1}{2} \Delta R_P \sin^2 \theta_0 \sin 2\varphi_0,$$

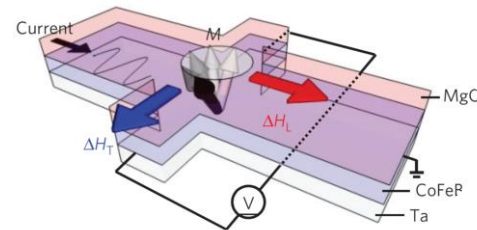
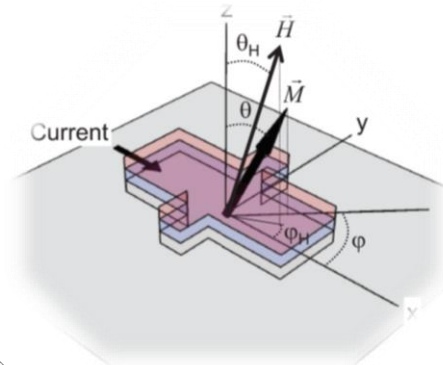
$$B_\theta = \frac{1}{2} (-\Delta R_A \sin \theta_0 + \Delta R_P \sin 2\theta_0 \sin 2\varphi_0) \Delta \theta,$$

$$B_\varphi = \Delta R_P \sin^2 \theta_0 \cos 2\varphi_0 \Delta \varphi.$$

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"Quantitative characterization of the spin-orbit torque using harmonic Hall voltage measurements",  
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"Layer thickness dependence of the current-induced effective field vector in Ta | CoFeB | MgO",  
NATURE MATERIALS **12**, 240 (2013)



### Out-of-plane magnetization

$$V_{XY} = R_{XY} I \quad V_{XY} = V_0 + V_\omega \sin \omega t + V_{2\omega} \cos 2\omega t,$$

$$I = \Delta I \sin \omega t$$

$$V_\omega \approx \pm \frac{1}{2} \Delta R_A \left[ 1 - \frac{1}{2} \left( \frac{H \sin \theta_H}{H_K \pm H \cos \theta_H} \right)^2 \right] \Delta I$$

$$V_{2\omega} \approx -\frac{1}{4} [\mp \Delta R_A (\Delta H_X \cos \varphi_H + \Delta H_Y \sin \varphi_H) + 2 \Delta R_P (-\Delta H_X \sin \varphi_H + \Delta H_Y \cos \varphi_H) \cos 2\varphi_H] \frac{H \sin \theta_H}{(H_K \pm H \cos \theta_H)^2} \Delta I$$

$$B \equiv \left( \frac{\partial V_{2\omega}}{\partial H} / \frac{\partial^2 V_\omega}{\partial H^2} \right)$$

$$= -\frac{1}{2} \left[ \left( \Delta H_X \mp 2 \frac{\Delta R_P}{\Delta R_A} \cos 2\varphi_H \Delta H_Y \right) \cos \varphi_H + \left( \Delta H_Y \pm 2 \frac{\Delta R_P}{\Delta R_A} \cos 2\varphi_H \Delta H_X \right) \sin \varphi_H \right]$$

$$\Delta H_X = -2 \frac{(B_X \pm 2\xi B_Y)}{1 - 4\xi^2} \quad \xi \equiv \frac{\Delta R_P}{\Delta R_A}$$

$$\Delta H_Y = -2 \frac{(B_Y \pm 2\xi B_X)}{1 - 4\xi^2} \quad B_X \equiv \left( \frac{\partial V_{2\omega}}{\partial H} / \frac{\partial^2 V_\omega}{\partial H^2} \right) |_{\vec{H} \parallel \hat{x}}$$

$$B_Y \equiv \left( \frac{\partial V_{2\omega}}{\partial H} / \frac{\partial^2 V_\omega}{\partial H^2} \right) |_{\vec{H} \parallel \hat{y}}$$

### LANDAU-LIFSHITZ-GILBERT (LLG) EQUATION

$$\frac{\partial \hat{m}}{\partial t} = -\gamma \hat{m} \times \left( -\frac{\partial E}{\partial \vec{M}} + \Delta \vec{H} \right) + \alpha \hat{m} \times \frac{\partial \hat{m}}{\partial t}$$

$$\frac{\partial \hat{m}}{\partial t} = -\gamma \hat{m} \times \left( -\frac{\partial E}{\partial \vec{M}} + a_J (\hat{m} \times \hat{p}) + b_J \hat{p} \right) + \alpha \hat{m} \times \frac{\partial \hat{m}}{\partial t}$$

$\hat{p}$  - represents the magnetization direction of the reference layer in the STT case  
or  
average spin direction of electrons diffusing into the magnetic layer in SOT case

$$|H_A| \ll |H \sin \theta_H|$$

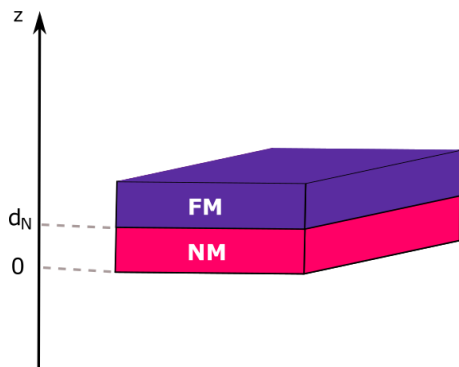
$$\varphi_0 = \varphi_H$$

# PHENOMENOLOGICAL DESCRIPTION OF SOTs

## MOTIVATION:

J. Kim, J. Sinha, S. Mitani, M. Hayashi, S. Takahashi, S. Maekawa, M. Yamanouchi, and H. Ohno, **Anomalous temperature dependence of current-induced torques in CoFeB/MgO heterostructures with Ta-based underlayers**, PHYSICAL REVIEW B **89**, 174424 (2014)

## DRIFT-DIFFUSION FORMALISM



$$\vec{J}_N = \dot{J}_N \hat{x}$$

$$Q_{iz}(z) = -\frac{1}{2|e|\rho_N} \frac{\partial}{\partial z} \delta\mu_i + \theta_{SH} (\hat{e}_i \times \vec{J}_N)_z$$

$$\delta\vec{\mu}(z) = \vec{A} \exp[-z/\lambda_N] + \vec{B} \exp[z/\lambda_N]$$

$$Q_{iz}^{N|F} = -\frac{1}{2|e|} \text{Re}[G_{\text{MIX}}] (\hat{m} \times \hat{m} \times \delta\vec{\mu}(z=d))_i - \frac{1}{2|e|} \text{Im}[G_{\text{MIX}}] (\hat{m} \times \delta\vec{\mu}(z=d))_i,$$

BOUNDARY CONDITIONS:

$$Q_{iz}(z=0) = 0,$$

$$Q_{iz}(z=d) = Q_{iz}^{N|F}$$

$$\Delta H_j = -\frac{\hbar}{2|e|t_F M_S} (\hat{m} \times \vec{Q}_z^{N|F})_j$$

$$\Delta H_x = -\theta_{SH} \frac{\hbar}{2|e|} \frac{J_N}{M_{StF}} \left(1 - \frac{1}{\cosh(d/\lambda_N)}\right) \left[ \frac{(1+g_r)g_r + g_i^2}{(1+g_r)^2 + g_i^2} \right] \text{sgn}(\hat{m} \times \hat{e}_y)_x,$$

$$\Delta H_y = -\theta_{SH} \frac{\hbar}{2|e|} \frac{J_N}{M_{StF}} \left(1 - \frac{1}{\cosh(d/\lambda_N)}\right) \left[ \frac{g_i}{(1+g_r)^2 + g_i^2} \right]$$

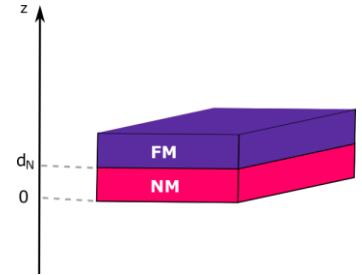
$$g_r = \text{Re}[G_{\text{MIX}}] \rho_N \lambda_N \coth\left(\frac{d}{\lambda_N}\right)$$

$$g_i = \text{Im}[G_{\text{MIX}}] \rho_N \lambda_N \coth\left(\frac{d}{\lambda_N}\right)$$

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## RESULTS

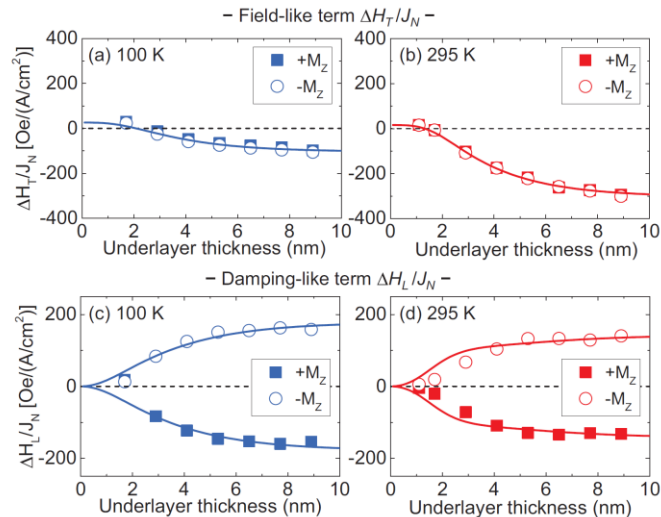


FIG. 6. (Color online) Underlayer thickness dependence of (a) and (b)  $\Delta H_T/J_N$  and (c) and (d)  $\Delta H_L/J_N$  for the TaN underlayer film. The measurement temperature is 100 K for (a) and (c) and RT ( $\sim 295$  K) for (b) and (d). Solid lines are calculated using Eqs. (7) and (8) with the following parameters:  $M_S = 1200 \text{ emu/cm}^3$ ,  $\rho_N = 395 \mu\Omega\text{-cm}$ ,  $\lambda_N = 2.5 \text{ nm}$ ,  $\theta_{SH} = -0.08$ , and the real and imaginary parts of the spin mixing conductance ( $G_{\text{MIX}}$ ), which are shown by the solid symbols in Fig. 7(a).

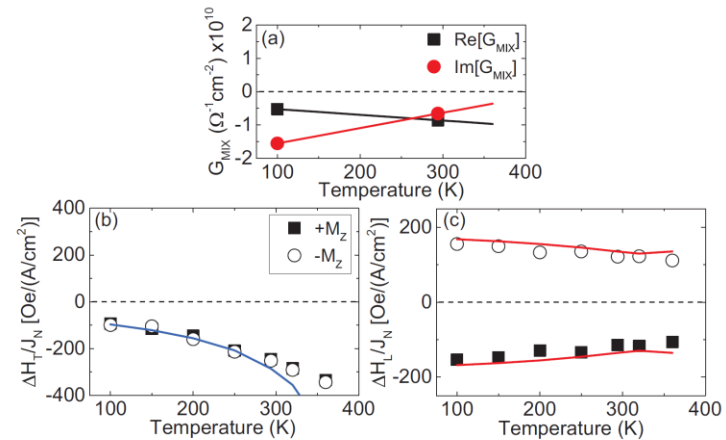


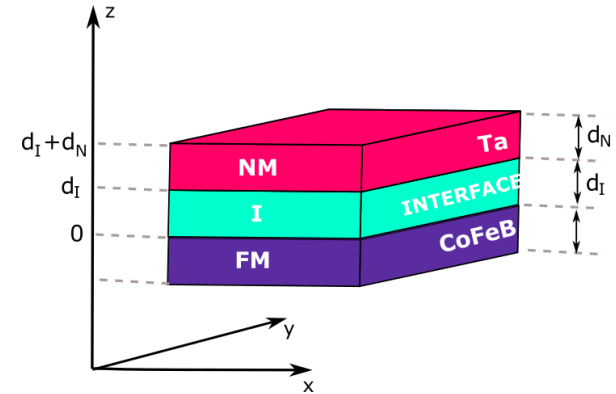
FIG. 7. (Color online) (a) Temperature dependence of the real and imaginary parts of the spin mixing conductance ( $G_{\text{MIX}}$ ) obtained by the fitting shown in Fig. 6. Linear fit to the data (symbols) is shown by the solid line. Temperature dependence of (b)  $\Delta H_T/J_N$  and (c)  $\Delta H_L/J_N$  for the TaN underlayer film with  $d \sim 8.9 \text{ nm}$ . Solid lines are calculated using Eqs. (7) and (8) with the following parameters:  $M_S = 1200 \text{ emu/cm}^3$ ,  $\rho_N = 395 \mu\Omega\text{-cm}$ ,  $\lambda_N = 2.5 \text{ nm}$ ,  $\theta_{SH} = -0.08$ , and the interpolated real and imaginary parts of  $G_{\text{MIX}}$  shown by the solid lines in (a).

# PHENOMENOLOGICAL DESCRIPTION OF SOTs

## □ EFFECTS ON INTERFACE

The NM layer and the FM layer affect the electronic structure of each other close to the interface

- the magnetic proximity effect can induce a magnetic moment in the NM layer (the material with strong SOC)
  - the spin-orbit proximity effect can induce spin-orbit effects in the FM layer
  - lattice mismatch between materials: thickness fluctuations, formation of dislocation
  - .....
- ✓ **spin backflow** (even from a „well-ordered” interface)
  - ✓ **spin memory loss**  
due to intermixing and disorder at the NM|FM interface



# PHENOMENOLOGICAL DESCRIPTION OF SOTs

## □ EFFECTS ON INTERFACE: TRILAYER SPIN DIFFUSION MODEL

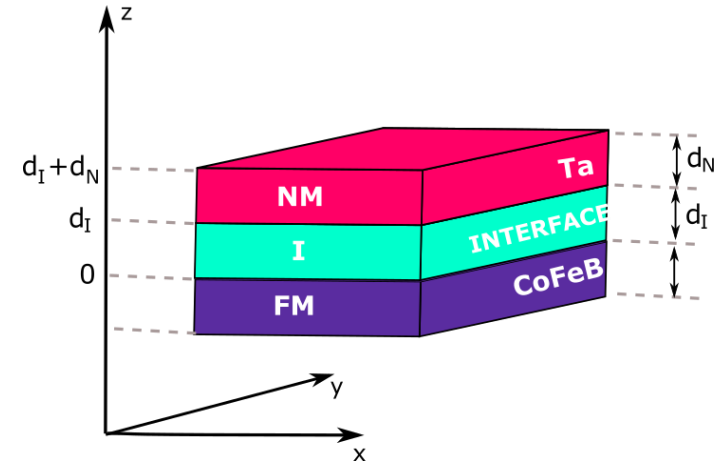
$$\vec{j}_s^N(z) = -\frac{1}{2|e|\rho_N} \frac{\partial \vec{\mu}_s^N(z)}{\partial z} - \theta_{SH} J_N \hat{y}$$

$$\frac{\partial^2 \vec{\mu}_s^N(z)}{\partial z^2} = \frac{\vec{\mu}_s^N(z)}{\lambda_{s,N}^2} \quad \vec{\mu}_s^N(z) = \vec{C} \exp\left(-\frac{z}{\lambda_N}\right) + \vec{D} \exp\left(\frac{z}{\lambda_N}\right)$$

$$\vec{j}_s^I(z) = -\frac{1}{2|e|\rho_I} \frac{\partial \vec{\mu}_s^I(z)}{\partial z}$$

$$\frac{\partial^2 \vec{\mu}_s^I(z)}{\partial z^2} = \frac{\vec{\mu}_s^I(z)}{\lambda_{s,I}^2} \quad \vec{\mu}_s^I(z) = \vec{A} \exp\left(-\frac{z}{\lambda_I}\right) + \vec{B} \exp\left(\frac{z}{\lambda_I}\right)$$

$$|e|\vec{j}_s^{F|I} = G_r \hat{m} \times \hat{m} \times \vec{\mu}_s^I(0) + G_i \hat{m} \times \vec{\mu}_s^I(0)$$



BOUNDARY CONDITIONS:

$$\vec{j}_s^N(z = d_I) = \vec{j}_s^I(z = d_I),$$

$$\vec{j}_s^I(z = 0) = \vec{j}_s^{F|I},$$

$$\vec{j}_s^N(z = d_I + d_N) = 0,$$

$$\vec{\mu}_s^I(z = d_I) = \vec{\mu}_s^N(z = d_I)$$

$$\begin{aligned} \vec{\mu}_s^I(0) = & 2|e|\theta_{SH} J_N \hat{y} \frac{\tanh\left(\frac{d_N}{2\lambda_N}\right) \operatorname{csch}\left(\frac{d_I}{\lambda_I}\right)}{\frac{1}{\rho_I \lambda_I} \coth\left(\frac{d_N}{\lambda_N}\right) + \frac{1}{\rho_N \lambda_N} \coth\left(\frac{d_I}{\lambda_I}\right)} \\ & + 2|e|\vec{j}_s^{F|I} \frac{\coth\left(\frac{d_N}{\lambda_N}\right) \coth\left(\frac{d_I}{\lambda_I}\right) + \frac{\rho_I \lambda_I}{\rho_N \lambda_N}}{\frac{1}{\rho_I \lambda_I} \coth\left(\frac{d_N}{\lambda_N}\right) + \frac{1}{\rho_N \lambda_N} \coth\left(\frac{d_I}{\lambda_I}\right)} \end{aligned}$$

# PHENOMENOLOGICAL DESCRIPTION OF SOTs

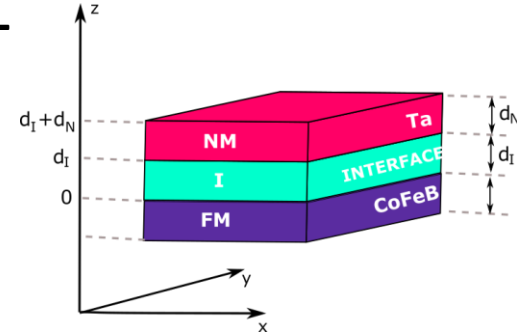
## □ EFFECTS ON INTERFACE: TRILAYER SPIN DIFFUSION MODEL

### DAMPING-LIKE AND FIELD-LIKE TORQUE EFFICIENCY:

$$\xi_{DL} \equiv \frac{2|e|\mu_0 M_S t_F}{\hbar J_N} \Delta H_L \quad \xi_{FL} \equiv \frac{2|e|\mu_0 M_S t_F}{\hbar J_N} \Delta H_T$$

$$\xi_{DL} = -\theta_{SH} \frac{\tanh(\frac{d_N}{2\lambda_N}) \operatorname{csch}(\frac{d_I}{\lambda_I})}{\coth(\frac{d_N}{\lambda_N}) \coth(\frac{d_I}{\lambda_I}) + \frac{\rho_I \lambda_I}{\rho_N \lambda_N}} \frac{g_r (1 + g_r) + g_i^2}{(1 + g_r)^2 + g_i^2} m_z$$

$$\xi_{FL} = -\theta_{SH} \frac{\tanh(\frac{d_N}{2\lambda_N}) \operatorname{csch}(\frac{d_I}{\lambda_I})}{\coth(\frac{d_N}{\lambda_N}) \coth(\frac{d_I}{\lambda_I}) + \frac{\rho_I \lambda_I}{\rho_N \lambda_N}} \frac{g_i}{(1 + g_r)^2 + g_i^2}$$



$$g_{r,i} = 2G_{r,i} \frac{\coth(\frac{d_N}{\lambda_N}) \coth(\frac{d_I}{\lambda_I}) + \frac{\rho_I \lambda_I}{\rho_N \lambda_N}}{\frac{1}{\rho_I \lambda_I} \coth(\frac{d_N}{\lambda_N}) + \frac{1}{\rho_N \lambda_N} \coth(\frac{d_I}{\lambda_I})}$$

$$G_i = \operatorname{Im}\{G_{\text{mix}}\}, G_r = \operatorname{Re}\{G_{\text{mix}}\}$$

### ▪ WITHOUT INTERFACE LAYER

$$\xi_{DL} = -\theta_{SH} \left( 1 - \frac{1}{\cosh(\frac{d}{\lambda_N})} \right) \frac{(1 + g_r)g_r + g_i^2}{(1 + g_r)^2 + g_i^2}$$

$$\xi_{FL} = -\theta_{SH} \left( 1 - \frac{1}{\cosh(\frac{d}{\lambda_N})} \right) \frac{g_i}{(1 + g_r)^2 + g_i^2}$$

$$g_{r,i} = G_{r,i} \rho_N \lambda_N \coth(d/\lambda_N)$$

# PHENOMENOLOGICAL DESCRIPTION OF SOTs

## EFFECTS ON INTERFACE: TRILAYER SPIN DIFFUSION MODEL – RESULTS

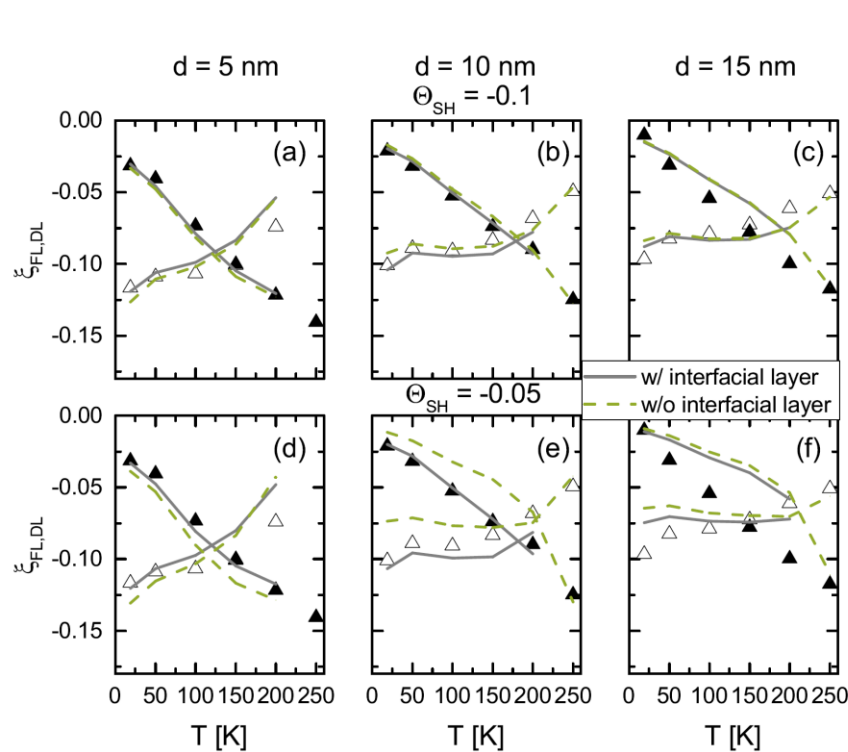
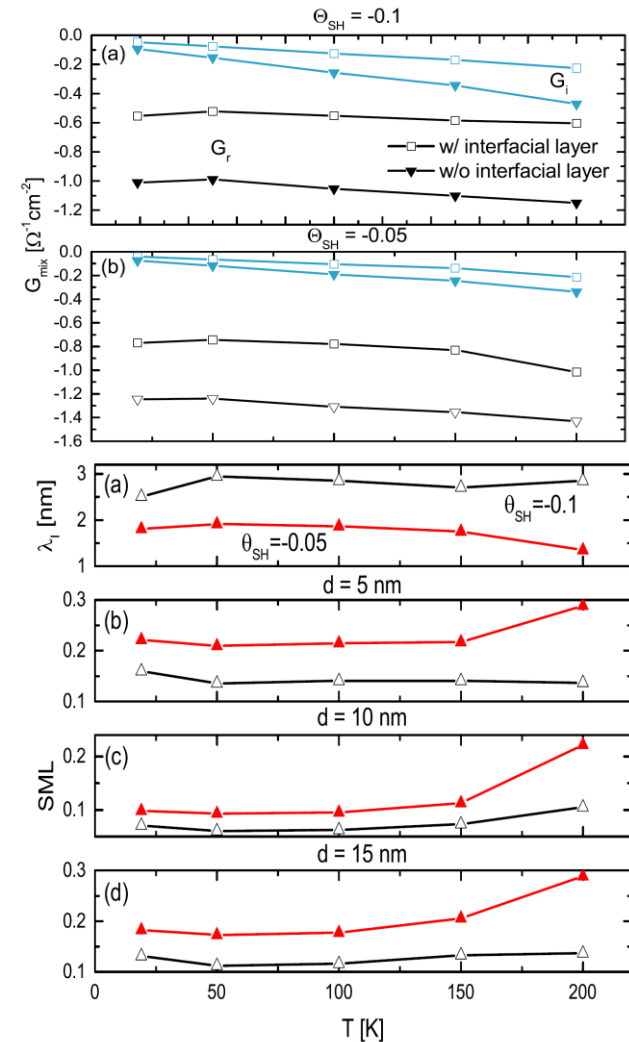


FIG. 6: Spin-torque efficiencies with theoretical fit for the case of additional and no interfacial layer in the model for indicated values of spin Hall angle  $\theta_{SH}$  and indicated values of Ta underlayer thickness for Ta spin diffusion length  $\lambda_N = 2.5$  nm.





# TRILAYER SPIN DIFFUSION MODEL : SUMMARY

- $\text{Im}[G_{\text{MIX}}]$  comparable in size to its real counterpart
  - ✓ large angle rotation of the spin direction of spin current
  - ✓ presence of spin Hall torque
- **Negative  $\text{Re}[G_{\text{MIX}}]$  !!!**
  - ✓ model failure
  - ✓ poor band matching between NM and the FM layers
  - ✓ flow of spin current from the FM layer to the NM layer



AHE or SHE in FM layer should be checked !

# ANOMALOUS HALL EFFECT IN Ta|CoFeB

JOURNAL OF APPLIED PHYSICS **113**, 17C717 (2013)



## The anomalous Hall effect in the perpendicular Ta/CoFeB/MgO thin films

S. B. Wu,<sup>1,2</sup> T. Zhu,<sup>1,a)</sup> X. F. Yang,<sup>2</sup> and S. Chen<sup>2</sup>

<sup>1</sup>Institute of Physics and Beijing National Laboratory for Condensed Matter Physics, Chinese Academy of Sciences, Beijing 100190, People's Republic of China

<sup>2</sup>Department of Electronic Science and Technology, Huazhong University of Science and Technology, Wuhan 430074, People's Republic of China

(Presented 17 January 2013; received 2 November 2012; accepted 20 December 2012; published online 25 March 2013)

The anomalous Hall effect (AHE) in the perpendicular Ta/CoFeB/MgO thin film has been investigated. Between the AHE coefficient ( $R_S$ ) and longitudinal resistivity ( $\rho_{xx}$ ), a linear behavior of  $R_S/\rho_{xx}$  versus  $\rho_{xx}$  can be found. Moreover, the conductivity of the film is about  $5 \times 10^3$  S/cm, which suggests that AHE in the Ta/CoFeB/MgO film be dominated by the intrinsic or scattering-independent mechanism. © 2013 American Institute of Physics. [<http://dx.doi.org/10.1063/1.4796192>]

APPLIED PHYSICS LETTERS **104**, 202404 (2014)



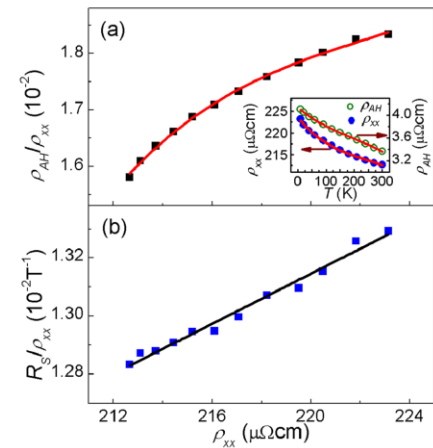
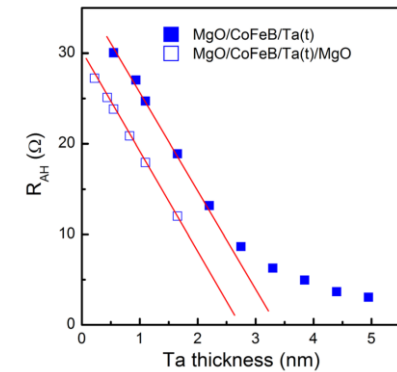
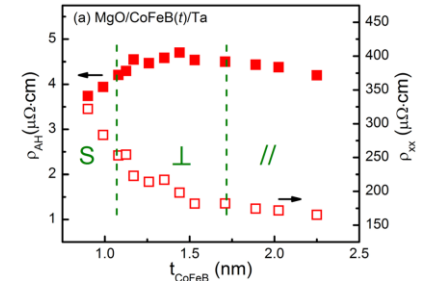
## Giant linear anomalous Hall effect in the perpendicular CoFeB thin films

T. Zhu,<sup>a)</sup> P. Chen, Q. H. Zhang, R. C. Yu, and B. G. Liu

Institute of Physics and Beijing National Laboratory for Condensed Matter Physics, Chinese Academy of Sciences, Beijing 100190, People's Republic of China

(Received 26 March 2014; accepted 7 May 2014; published online 20 May 2014)

Giant anomalous Hall effect in a perpendicular CoFeB thin film has been reported, which satisfies large anomalous Hall resistivity and low switching field at same time. The largest sensitivity of linear anomalous Hall effect reaches  $2376 \Omega/\text{kOe}$ , which is 21 times larger than that of the best semiconductor. Our results suggest the low cost MgO/CoFeB/Ta thin film can be a potential candidate for highly sensitive magnetic field detecting. © 2014 AIP Publishing LLC. [<http://dx.doi.org/10.1063/1.4878538>]



# TRILAYER SPIN DIFFUSION MODEL : SUMMARY

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  - ✓ large angle rotation of the spin direction of spin current
  - ✓ presence of spin Hall torque
- **Negative  $\text{Re}[G_{\text{MIX}}]$  !!!**
  - ✓ **model failure**
  - ✓ poor band matching between NM and the FM layers
  - ✓ flow of spin current from the FM layer to the NM layer



AHE or SHE in FM layer should be checked !

## ➔ FURTHER MODIFICATION OF TRILAYER SPIN DIFFUSION MODEL

$$\vec{j}_s^N(z) = -\frac{1}{2|e|\rho_N} \frac{\partial \vec{\mu}_s^N(z)}{\partial z} - \theta_{SH} J_N \hat{y}$$

$$\frac{\partial^2 \vec{\mu}_s^N(z)}{\partial z^2} = \frac{\vec{\mu}_s^N(z)}{\lambda_{s,N}^2} \quad \vec{\mu}_s^N(z) = \vec{C} \exp\left(-\frac{z}{\lambda_N}\right) + \vec{D} \exp\left(\frac{z}{\lambda_N}\right)$$

$$\vec{j}_s^I(z) = -\frac{1}{2|e|\rho_I} \frac{\partial \vec{\mu}_s^I(z)}{\partial z} \boxed{-(\theta_{SH} + \Delta\theta_{SH}) J_{Iy} ???}$$

$$\frac{\partial^2 \vec{\mu}_s^I(z)}{\partial z^2} = \frac{\vec{\mu}_s^I(z)}{\lambda_{s,I}^2} \quad \vec{\mu}_s^I(z) = \vec{A} \exp\left(-\frac{z}{\lambda_I}\right) + \vec{B} \exp\left(\frac{z}{\lambda_I}\right)$$

$$|e|j_s^{FI} = G_r \hat{m} \times \hat{m} \times \vec{\mu}_s^I(0) + G_i \hat{m} \times \vec{\mu}_s^I(0)$$

SOC at the interface !

SOC in the FM ?

# ANOTHER APPROACHES

## Spin Transport at Interfaces with Spin-Orbit Coupling: Phenomenology

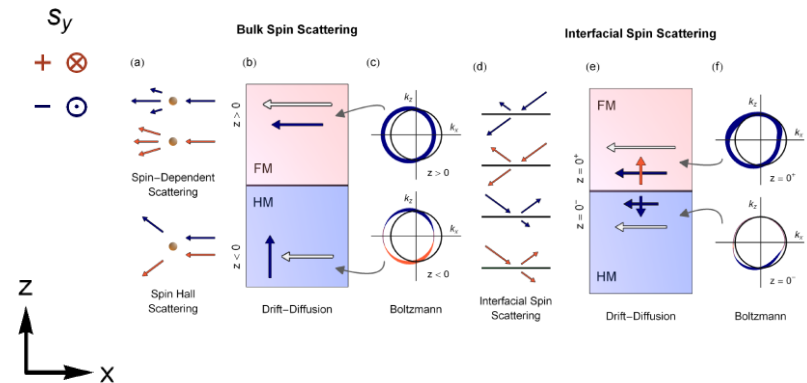
V. P. Amin<sup>1,2,\*</sup> and M. D. Stiles<sup>2</sup>

$$\mathbf{j}_s(z) = \frac{\sigma^{\text{FM}}}{e} P \hat{\mathbf{m}} \frac{\partial \mu_c(z)}{\partial z} - \frac{\sigma^{\text{FM}}}{e} \frac{\partial \boldsymbol{\mu}_s(z)}{\partial z}$$

$$\frac{1}{e N_s^{\text{FM}}} \frac{\partial \mathbf{j}_s(z)}{\partial z} = -\frac{1}{\tau_{\text{sf}}^{\text{FM}}} \boldsymbol{\mu}_s(z) - \frac{1}{\tau_{\text{ex}}} \boldsymbol{\mu}_s(z) \times \hat{\mathbf{m}} - \frac{1}{\tau_{\text{dp}}} \hat{\mathbf{m}} \times \boldsymbol{\mu}_s(z) \times \hat{\mathbf{m}}$$

$$\mathbf{j}_s(z) = -\frac{\sigma^{\text{HM}}}{e} \frac{\partial \boldsymbol{\mu}_s(z)}{\partial z} + \mathbf{j}_s^{\text{sH}} \quad \mathbf{j}_s^{\text{sH}} = \sigma_{\text{sH}} \mathbf{E} \times \hat{\mathbf{z}}$$

$$\frac{1}{e N_s^{\text{HM}}} \frac{\partial \mathbf{j}_s(z)}{\partial z} = -\frac{1}{\tau_{\text{sf}}^{\text{HM}}} \boldsymbol{\mu}_s(z)$$



### BOUNDARY CONDITIONS:

$$\mathbf{j}_{\perp}(0^-) = \mathbf{G}_R \boldsymbol{\mu}_{\perp}(0^-) + \mathbf{j}_{\perp}^{\text{E}}(0^-) \quad \mathbf{j}_{\perp}^{\text{E}}(0^-) = \boldsymbol{\sigma}(\hat{\mathbf{m}}) \tilde{\mathbf{E}}$$

$$\mathbf{j}_{\perp}(0^+) = \boldsymbol{\Gamma}^{\text{FM}} \boldsymbol{\mu}_{\perp}(0^+) + \mathbf{j}_{\perp}^{\text{E}}(0^+) \quad \mathbf{j}_{\perp}^{\text{E}}(0^+) = \boldsymbol{\gamma}^{\text{FM}}(\hat{\mathbf{m}}) \tilde{\mathbf{E}}$$

$$\boldsymbol{\tau}^{\text{mag}} = (\mathbf{G}_R - \boldsymbol{\Gamma}^{\text{FM}}) \boldsymbol{\mu}_{\perp}(0^-) + \boldsymbol{\tau}^{\text{E}} \quad \boldsymbol{\tau}^{\text{E}} = \boldsymbol{\gamma}^{\text{mag}}(\hat{\mathbf{m}}) \tilde{\mathbf{E}}$$

spin currents generated by interfacial spin-orbit scattering

additional spin-torque due to spin polarization that arises at the interface

the torque on magnetization at the interface

$$V(\mathbf{r}) = \frac{\hbar^2 k_F}{m} \delta(z) (u_0 + u_{\text{ex}} \boldsymbol{\sigma} \cdot \hat{\mathbf{m}} + u_R \boldsymbol{\sigma} \cdot (\hat{\mathbf{k}} \times \hat{\mathbf{z}}))$$

THE RASHBA MODEL OF SOC

- conductance matrix -  $\mathbf{G}_R = \begin{pmatrix} \text{Re}[G_{\uparrow\downarrow}] & -\text{Im}[G_{\uparrow\downarrow}] \\ \text{Im}[G_{\uparrow\downarrow}] & \text{Re}[G_{\uparrow\downarrow}] \end{pmatrix}$
- torque tensor -  $\boldsymbol{\Gamma}^{\text{FM}}$
- conductivity tensor -  $\boldsymbol{\sigma}(\hat{\mathbf{m}})$
- torque tensors -  $\boldsymbol{\gamma}^{\text{mag}}(\hat{\mathbf{m}})$   
 $\boldsymbol{\gamma}^{\text{FM}}(\hat{\mathbf{m}})$

# ANOTHER APPROACHES

PRL 114, 126602 (2015)

PHYSICAL REVIEW LETTERS

week ending  
27 MARCH 2015

## Spin Pumping in the Presence of Spin-Orbit Coupling

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(Received 20 October 2014; published 26 March 2015)

Spin pumping and related phenomena have been observed recently in heavy metals and topological insulators, where the spin-orbit coupling plays an essential role. We have developed a spin-pumping formalism that explicitly includes the spin-orbit coupling at interfaces and disorder in the layers. Spin pumping across an interface with spin-orbit coupling and the attendant backflow are treated on an equal footing. We resolve some long-standing issues on the conflicting conclusions about the spin-diffusion length for Pt, and the origin of spin-memory loss at interfaces with heavy metals. In addition, we predict some heretofore unanticipated spin-pumping phenomena.

DOI: 10.1103/PhysRevLett.114.126602

PACS numbers: 72.25.Mk, 73.40.-c

- ✓ spin pumping conductivity is given by retarded and advanced Green functions

$$\mathbf{j}^s = \frac{\hbar}{4\pi} \left( g_r \mathbf{m} \times \frac{d\mathbf{m}}{dt} - g_i \frac{d\mathbf{m}}{dt} \right)$$

$$\mathbf{j}_i(\mathbf{r}, t) = \frac{\hbar}{4\pi} \left[ \Gamma_i^{re}(r) \mathbf{m} \times \frac{d\mathbf{m}}{dt} - \Gamma_i^{im}(r) \frac{d\mathbf{m}}{dt} \right]$$

$$\Gamma_i(\mathbf{r}) = \Gamma_i^{re}(\mathbf{r}) + i\Gamma_i^{im}(\mathbf{r}) \quad \Gamma_i(\mathbf{r}) = \frac{J_{\text{ex}} \hbar^2}{m_e} \int_{\text{FM}} d^3 r' g_{\uparrow}^R(\mathbf{r}, \mathbf{r}') \vec{\partial}_i g_{\downarrow}^A(\mathbf{r}', \mathbf{r})$$

- ✓ disordered included explicitly
- ✓ SOC at the interface
- ✓ backflow current

# ANOTHER APPROACHES

## Spin Transport at Interfaces with Spin-Orbit Coupling: Phenomenology

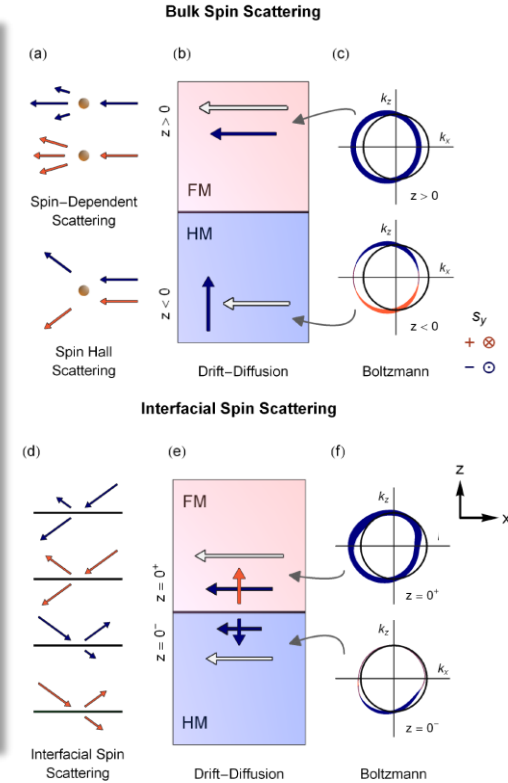
V. P. Amin<sup>1,2,\*</sup> and M. D. Stiles<sup>2</sup>

<sup>1</sup>Maryland NanoCenter, University of Maryland, College Park, MD 20742

<sup>2</sup>Center for Nanoscale Science and Technology, National Institute of Standards and Technology, Gaithersburg, Maryland 20899, USA

(Dated: April 25, 2016)

Spin transport remains poorly understood in multilayer systems with interfacial spin-orbit coupling. While the important consequences of interfacial spin-orbit coupling can be captured by a spin-dependent Boltzmann equation, currently they cannot be captured by drift-diffusion models, which are the primary tools used for analyzing experiments. Here we present boundary conditions suitable for drift-diffusion models that capture the phenomenology of spin-orbit torques at interfaces. We compare solutions of the drift-diffusion equations using these boundary conditions to solutions of the spin-dependent Boltzmann equation for a heavy metal/ferromagnet bilayer. We find that the drift-diffusion equations predict spin torques in quantitative agreement with the Boltzmann equation and allow for a much simpler interpretation of the results. A key feature of these boundary conditions is their ability to capture the scattering that carriers experience while flowing along an interface. In the presence of interfacial spin-orbit coupling, this scattering generates spin currents that flow away from the interface. In heavy metal/ferromagnet bilayers, these spin currents provide an important mechanism for the creation of damping-like and field-like torques; they also lead to possible reinterpretations of experiments in which interfacial contributions to spin torques are thought to be suppressed.



$$\mathbf{j}_s(z) = \frac{\sigma^{\text{FM}}}{e} P \hat{\mathbf{m}} \frac{\partial \mu_c(z)}{\partial z} - \frac{\sigma^{\text{FM}}}{e} \frac{\partial \mu_s(z)}{\partial z}$$

$$\frac{1}{e N_s^{\text{FM}}} \frac{\partial \mathbf{j}_s(z)}{\partial z} = -\frac{1}{\tau_{\text{sf}}^{\text{FM}}} \boldsymbol{\mu}_s(z) - \frac{1}{\tau_{\text{ex}}} \boldsymbol{\mu}_s(z) \times \hat{\mathbf{m}} - \frac{1}{\tau_{\text{dp}}} \hat{\mathbf{m}} \times \boldsymbol{\mu}_s(z) \times \hat{\mathbf{m}}$$

$$\mathbf{j}_s(z) = -\frac{\sigma^{\text{HM}}}{e} \frac{\partial \mu_s(z)}{\partial z} + \mathbf{j}_s^{\text{SH}} \quad \mathbf{j}_s^{\text{SH}} = \sigma_{\text{SH}} \mathbf{E} \times \hat{\mathbf{z}}$$

$$\frac{1}{e N_s^{\text{HM}}} \frac{\partial \mathbf{j}_s(z)}{\partial z} = -\frac{1}{\tau_{\text{sf}}^{\text{HM}}} \boldsymbol{\mu}_s(z).$$

$$\mathbf{j}_\perp(0^-) = \mathbf{G}_R \boldsymbol{\mu}_\perp(0^-) + \mathbf{j}_\perp^{\text{E}}(0^-) \quad \mathbf{j}_\perp^{\text{E}}(0^-) = \sigma(\hat{\mathbf{m}}) \tilde{\mathbf{E}}$$

$$\mathbf{j}_\perp(0^+) = \Gamma^{\text{FM}} \boldsymbol{\mu}_\perp(0^-) + \mathbf{j}_\perp^{\text{E}}(0^+) \quad \mathbf{j}_\perp^{\text{E}}(0^+) = \gamma^{\text{FM}}(\hat{\mathbf{m}}) \tilde{\mathbf{E}}$$

$$\boldsymbol{\tau}^{\text{mag}} = (\mathbf{G}_R - \Gamma^{\text{FM}}) \boldsymbol{\mu}_\perp(0^-) + \boldsymbol{\tau}^{\text{E}} \quad \boldsymbol{\tau}^{\text{E}} = \gamma^{\text{mag}}(\hat{\mathbf{m}}) \tilde{\mathbf{E}}$$

$$\mathbf{G}_R = \begin{pmatrix} \text{Re}[G_{\uparrow\downarrow}] & -\text{Im}[G_{\uparrow\downarrow}] \\ \text{Im}[G_{\uparrow\downarrow}] & \text{Re}[G_{\uparrow\downarrow}] \end{pmatrix}$$

$$V(\mathbf{r}) = \frac{\hbar^2 k_F}{m} \delta(z) (u_0 + u_{\text{ex}} \boldsymbol{\sigma} \cdot \hat{\mathbf{m}} + u_R \boldsymbol{\sigma} \cdot (\hat{\mathbf{k}} \times \hat{\mathbf{z}}))$$